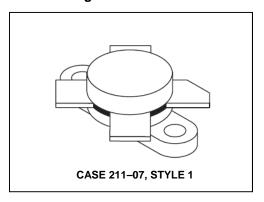


M/A-COM Products Released - Rev. 05202009

Designed for high gain driver and output linear amplifier stages in 1.5 to 30 MHz HF/SSB equipment.

- Specified 28 V, 30 MHz characteristics —
 Output power = 25 W (PEP)
 Minimum gain = 22 dB
 Efficiency = 35%
- Intermodulation distortion @ 25 W (PEP) —IMD = −30 dB (max)
- 100% tested for load mismatch at all phase angles with 30:1 VSWR
- Class A and AB characterization
- BLX 13 equivalent

Product Image



MAXIMUM RATINGS

MAAIMONI RATINOS			
Rating	Symbo	l Value	Unit
Collector–Emitter Voltage	V _{CEO}	35	Vdc
Collector-Base Voltage	V _{CBO}	65	Vdc
Emitter-Base Voltage	V _{EBO}	4.0	Vdc
Collector Current — Continuous	Ic	3.0	Adc
Withstand Current — 5 s		6.0	Adc
Total Device Dissipation @ T _C = 25°C (1) Derate above 25°C	P _D	70 0.4	Watts W/°C
Storage Temperature Range	T _{stg}	-65 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	R _{eJC}	2.5	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted.)

Symbol	Min	Тур	Max	Unit
	•		•	
V _{(BR)CEO}	35	_	_	Vdc
V _{(BR)CBO}	65	_	_	Vdc
V _{(BR)EBO}	4.0	_	_	Vdc
Ices	_	_	10	mAdc
	V(BR)CEO V(BR)CBO V(BR)EBO	V _{(BR)CEO} 35 V _{(BR)CBO} 65 V _{(BR)EBO} 4.0	V _{(BR)CEO} 35 — V _{(BR)CBO} 65 — V _{(BR)EBO} 4.0 —	V(BR)CEO 35 — — V(BR)CBO 65 — — V(BR)EBO 4.0 — —

NOTE:

(continued)

1. This device is designed for RF operation. The total device dissipation rating applies only when the device is operated as an RF amplifier.

typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available.

Commitment to produce in volume is not guaranteed.

[•] **Europe** Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.

MRF426



The RF Line NPN Silicon Power Transistor 25W(PEP), 30MHz, 28V

M/A-COM Products Released - Rev. 05202009

ELECTRICAL CHARACTERISTICS — continued	d (T _C = 25°C unless otherwise noted.)
--	---

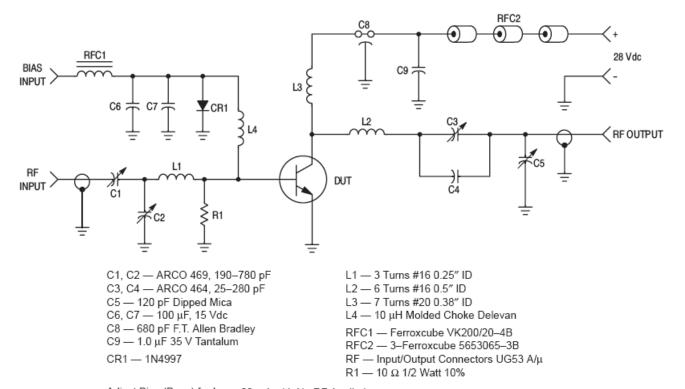
Characteristic	Symbol	Min	Тур	Max	Unit
ON CHARACTERISTICS	•	•			
DC Current Gain (I _C = 1.0 Adc, V _{CE} = 5.0 Vdc)	h _{FE}	10	35	_	_
DYNAMIC CHARACTERISTICS	•	•	•		
Output Capacitance (V _{CB} = 30 Vdc, I _E = 0, f = 1.0 MHz)	C _{ob}	_	60	80	pF
FUNCTIONAL TESTS (SSB)	•	•			
Common–Emitter Amplifier Gain (V _{CC} = 28 Vdc, P _{out} = 25 W (PEP), f1 = 30 MHz, f2 = 30.001 MHz, I _{CQ} = 25 mA)	G _{PE}	22	25	_	dB
Collector Efficiency (V _{CC} = 28 Vdc, P _{out} = 25 W (PEP), f1 = 30 MHz, f2 = 30.001 MHz, I _{CQ} = 25 mA)	η	35	_	_	%
Intermodulation Distortion (2) (V _{CC} = 28 Vdc, P _{out} = 25 W (PEP), f1 = 30 MHz, f2 = 30.001 MHz, I _{CQ} = 25 mA)	IMD _(d3)	_	-35	-30	dB
Load Mismatch (V _{CC} = 28 Vdc, P _{out} = 25 W (PEP), f1 = 30 MHz, f2 = 30.001 MHz, I _{CQ} = 25 mA, VSWR 30:1 at All Phase Angles)	Ψ	No Degradation in Output Power			
CLASS A PERFORMANCE					
Intermodulation Distortion (2) and Power Gain (V _{CC} = 28 Vdc, P _{out} = 8.0 W (PEP), f1 = 30 MHz, f2 = 30.001 MHz, I _{CQ} = 1.2 Adc)	G _{PE} IMD _(d3) IMD _(d5)		23.5 -40 -55		dB

NOTE:

2. To Mil-Std-1311 Version A, Test Method 2204B, Two Tone, Reference each Tone.



M/A-COM Products Released - Rev. 05202009



Adjust Bias (Base) for I_{CQ} = 20 mA with No RF Applied

Figure 1. 30 MHz Linear Test Circuit

• **Europe** Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
Visit www.macomtech.com for additional data sheets and product information.



M/A-COM Products Released - Rev. 05202009

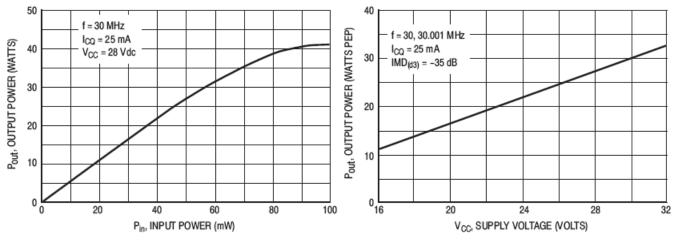


Figure 2. Output Power versus Input Power

Figure 3. Output Power versus Supply Voltage

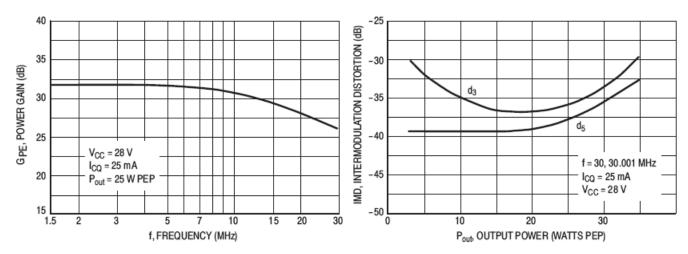


Figure 4. Power Gain versus Frequency

Figure 5. Intermodulation Distortion versus Output Power

[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300



M/A-COM Products Released - Rev. 05202009

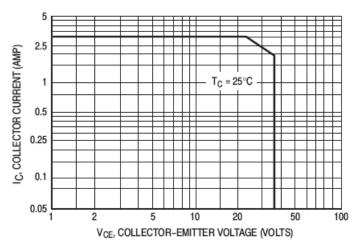


Figure 6. DC Safe Operating Area

• North America Tel: 800.366.2266 / Fax: 978.366.2266



M/A-COM Products Released - Rev. 05202009

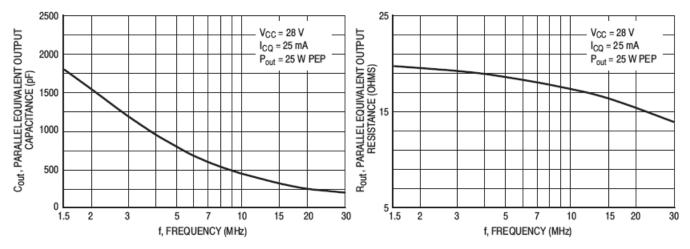


Figure 7. Output Capacitance versus Frequency

Figure 8. Output Resistance versus Frequency

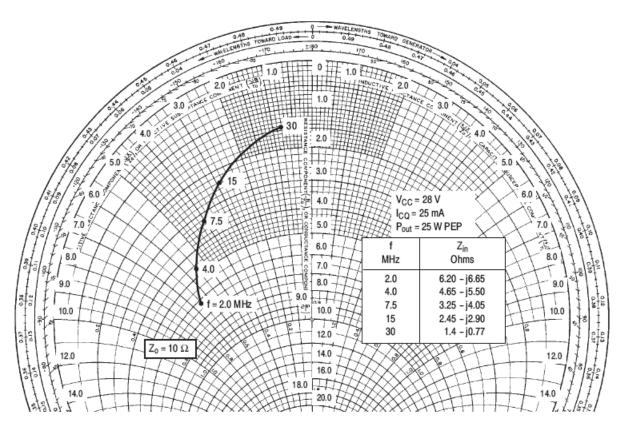


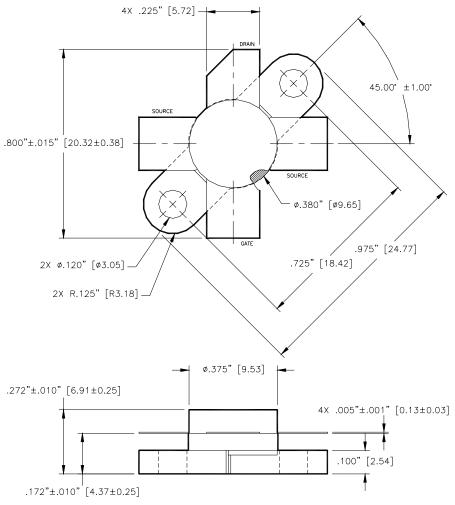
Figure 9. Series Equivalent Input Impedance

[•] **Europe** Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.



M/A-COM Products Released - Rev. 05202009



Unless otherwise noted, tolerances are inches $\pm .005$ " [millimeters ± 0.13 mm]

[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
Visit www.macomtech.com for additional data sheets and product information.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for RF Bipolar Transistors category:

Click to view products by MACOM manufacturer:

Other Similar products are found below:

MAPRST0912-50 MCH4016-TL-H MMBT5551-G PH3135-90S MRF10120 MRF587 15GN01CA-TB-E BFR 360L3 E6765 PH1214100EL PH1214-25M 2SA1257-5-TB-E MAPRST0912-350 MCH4014-TL-H MMBTH10-TP BFP 420F H6327 BFP 620F H7764 BFP 640F
H6327 BFP 720F H6327 BFP 740F H6327 BFR 340L3 E6327 BFR 360F H6765 BFR 740L3RH E6327 PH2729-25M MRF10031
NSVF4009SG4T1G DSC5G02D0L BFP 182R E7764 BFP405H6740XTSA1 MRF10350 MRF321 PH2729-65M MRF317 ASMA201
MCH4015-TL-H BF888H6327XTSA1 MMBT2222A-G BFP196WH6327XTSA1 BFP405FH6327XTSA1 BFP640ESDH6327XTSA1
BFR505T,115 BFU550WX BFU550XRR BFU580QX 55GN01FA-TL-H NSVF4020SG4T1G NSVF6003SB6T1G MMBT5179 MS1406
STBV32-AP BFG520,215